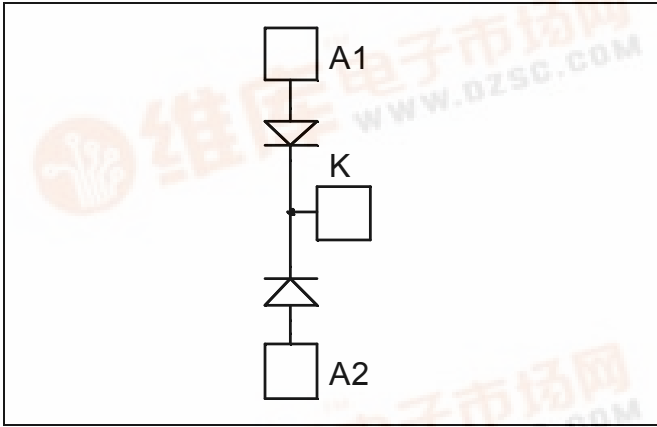


*Dual Common Cathode diodes  
Power Module*

$V_{CES} = 1200V$   
 $I_C = 400A @ T_c = 60^\circ C$

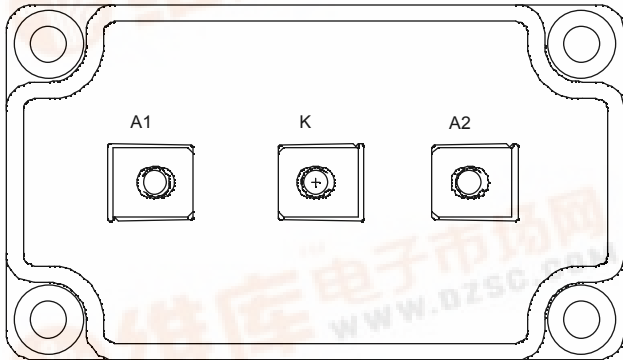


**Application**

- Uninterruptible Power Supply (UPS)
- Induction heating
- Welding equipment
- High speed rectifiers

**Features**

- Ultra fast recovery times
- Soft recovery characteristics
- High blocking voltage
- High current
- Low leakage current
- Very low stray inductance
  - Symmetrical design
  - M5 power connectors
- High level of integration



**Benefits**

- Outstanding performance at high frequency operation
- Low losses
- Low noise switching
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- RoHS Compliant

**Absolute maximum ratings**

Symbol	Parameter	Max ratings	Unit
$V_R$	Maximum DC reverse Voltage	1200	V
$V_{RRM}$	Maximum Peak Repetitive Reverse Voltage		
$I_{F(AV)}$	Maximum Average Forward Current	Duty cycle = 50% $T_C = 25^\circ C$	470
		$T_C = 60^\circ C$	400
$I_{F(RMS)}$	RMS Forward Current	Duty cycle = 50% $T_C = 45^\circ C$	500
$I_{FSM}$	Non-Repetitive Forward Surge Current	8.3ms $T_C = 45^\circ C$	3000

**CAUTION:** These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on [www.microsemi.com](http://www.microsemi.com)

All ratings @  $T_j = 25^\circ\text{C}$  unless otherwise specified

**Electrical Characteristics**

<i>Symbol</i>	<i>Characteristic</i>	<i>Test Conditions</i>		<i>Min</i>	<i>Typ</i>	<i>Max</i>	<i>Unit</i>
$V_F$	Diode Forward Voltage	$I_F = 400\text{A}$			2.4	3.0	V
		$I_F = 600\text{A}$			2.7		
		$I_F = 400\text{A}$	$T_j = 125^\circ\text{C}$		1.8		
$I_{RM}$	Maximum Reverse Leakage Current	$V_R = 1200\text{V}$	$T_j = 25^\circ\text{C}$			250	$\mu\text{A}$
			$T_j = 125^\circ\text{C}$			1000	
$C_T$	Junction Capacitance	$V_R = 1200\text{V}$			440		pF

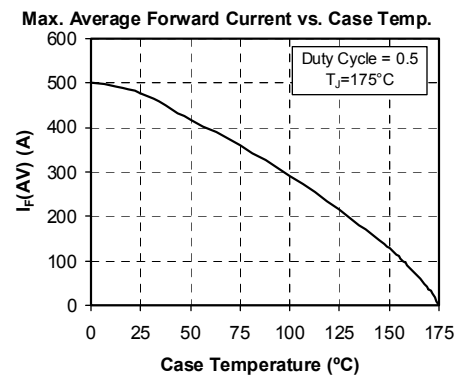
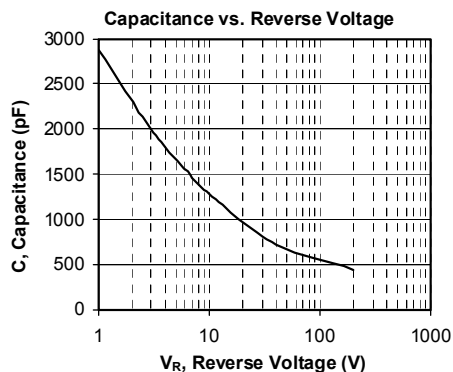
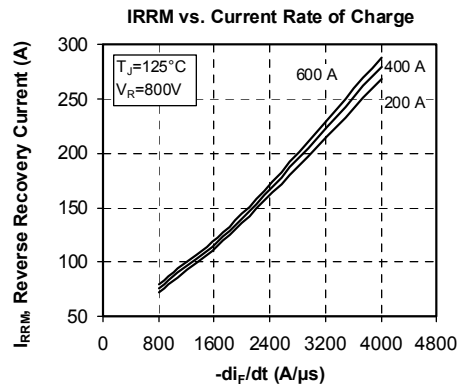
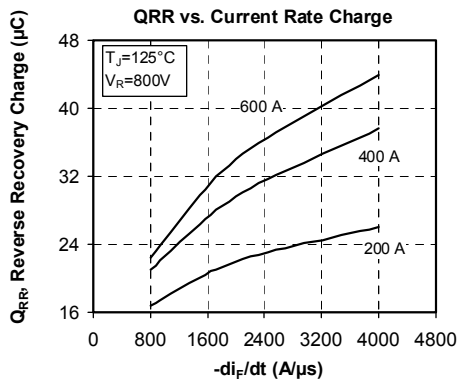
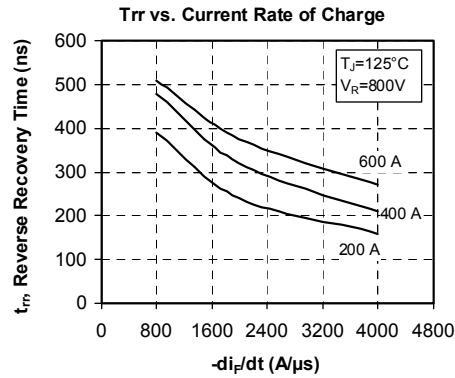
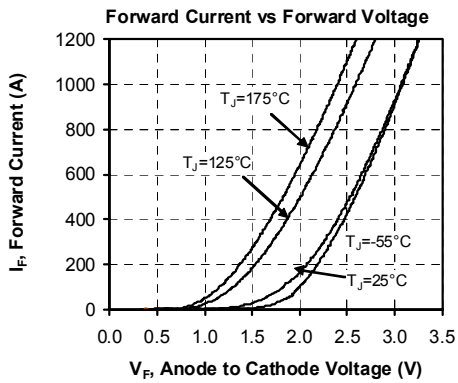
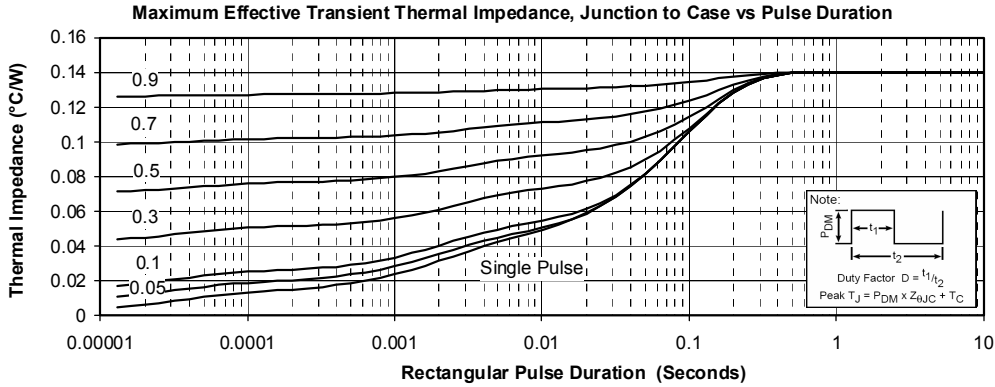
**Dynamic Characteristics**

<i>Symbol</i>	<i>Characteristic</i>	<i>Test Conditions</i>		<i>Min</i>	<i>Typ</i>	<i>Max</i>	<i>Unit</i>
$t_{rr}$	Reverse Recovery Time	$I_F = 1\text{A}, V_R = 30\text{V}$ $di/dt = 400\text{A}/\mu\text{s}$	$T_j = 25^\circ\text{C}$		45		ns
$t_{rr}$	Reverse Recovery Time		$T_j = 25^\circ\text{C}$		385		ns
			$T_j = 125^\circ\text{C}$		480		
$Q_{rr}$	Reverse Recovery Charge	$I_F = 400\text{A}$ $V_R = 800\text{V}$ $di/dt = 800\text{A}/\mu\text{s}$	$T_j = 25^\circ\text{C}$		4.2		$\mu\text{C}$
			$T_j = 125^\circ\text{C}$		20.9		
$I_{RRM}$	Reverse Recovery Current		$T_j = 25^\circ\text{C}$		24		A
			$T_j = 125^\circ\text{C}$		76		
$t_{rr}$	Reverse Recovery Time	$I_F = 400\text{A}$ $V_R = 800\text{V}$ $di/dt = 4000\text{A}/\mu\text{s}$	$T_j = 125^\circ\text{C}$		210		ns
$Q_{rr}$	Reverse Recovery Charge				38		$\mu\text{C}$
$I_{RRM}$	Reverse Recovery Current				280		A

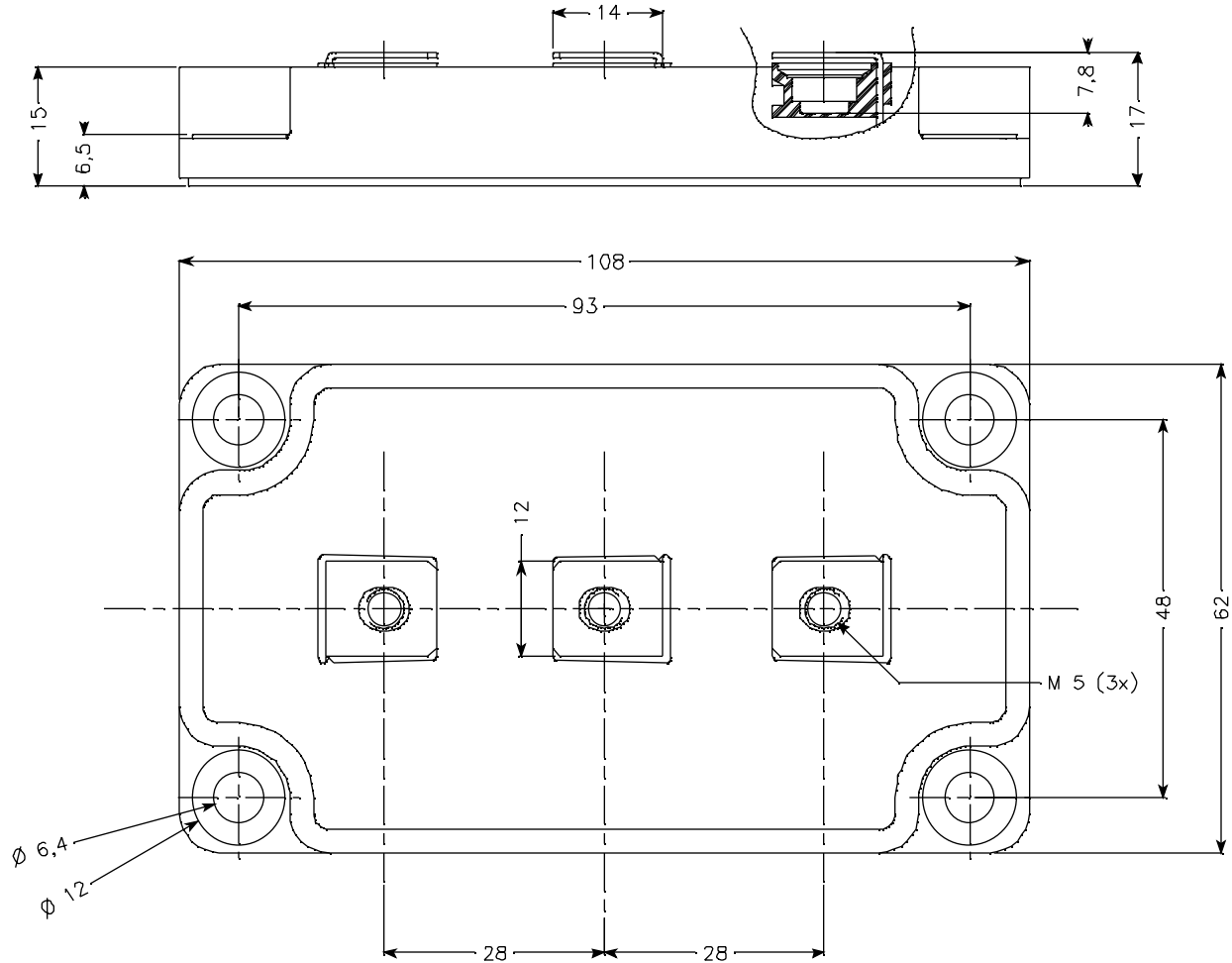
**Thermal and package characteristics**

<i>Symbol</i>	<i>Characteristic</i>	<i>Min</i>	<i>Typ</i>	<i>Max</i>	<i>Unit</i>	
$R_{thJC}$	Junction to Case Thermal Resistance			0.14	$^\circ\text{C}/\text{W}$	
$V_{ISOL}$	RMS Isolation Voltage, any terminal to case $t = 1\text{ min}$ , $I_{isol} < 1\text{mA}$ , 50/60Hz	2500			V	
$T_j$	Operating junction temperature range	-40		175	$^\circ\text{C}$	
$T_{STG}$	Storage Temperature Range	-40		125		
$T_C$	Operating Case Temperature	-40		100		
Torque	Mounting torque	To heatsink	M6	3	5	N.m
		For terminals	M5	2	3.5	
Wt	Package Weight			280	g	

## Typical Performance Curve



**SP6 Package outline** (dimensions in mm)



Microsemi reserves the right to change, without notice, the specifications and information contained herein

Microsemi's products are covered by one or more of U.S. patents 4,895,810 5,045,903 5,089,434 5,182,234 5,019,522 5,262,336 6,503,786 5,256,583 4,748,103 5,283,202 5,231,474 5,434,095 5,528,058 and foreign patents. U.S and Foreign patents pending. All Rights Reserved.